

February 2012

MJD47/50 NPN Epitaxial Silicon Transistor

Features

- High Voltage and High Reliability D-PAK for Surface Mount Applications
- Load Formed for Surface Mount Application (No Suffix)
- Straight Lead (I-PAK, "- I" Suffix)
- Electrically Similar to Popular TIP47 and TIP50



Absolute Maximum Ratings T_a = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Emitter Voltage		
	: MJD47	350	V
	: MJD50	500	V
V _{CEO}	Collector-Emitter Voltage		
	: MJD47	250	V
	: MJD50	400	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current (DC)	1	Α
I _{CP}	Collector Current (Pulse)	2	Α
I _B	Base Current	0.6	А
P _C	Collector Dissipation (T _C = 25°C)	15	W
	Collector Dissipation (T _a = 25°C)	1.56	W
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 65 to 150	°C

Ordering Information

Part Number	Marking	Package	Packing Method	Remarks
MJD47TF	MJD47	D-PAK	Tape & Reel	
MJD50TF	MJD50	D-PAK	Tape & Reel	

© 2012 Fairchild Semiconductor Corporation MJD47/50 Rev. B0 www.fairchildsemi.com

Electrical Characteristics $T_a = 25$ °C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
V _{CEO} (sus)	* Collector-Emitter Sustaining Voltage				
	: MJD47	$I_C = 30 \text{mA}, I_B = 0$	250		V
	: MJD50	$I_C = 30 \text{mA}, I_B = 0$	400		V
I _{CEO}	Collector Cut-off Current				
	: MJD47	$V_{CE} = 150V, I_{B} = 0$		0.2	mA
	: MJD50	$V_{CE} = 300V, I_{B} = 0$		0.2	mA
I _{CES}	Collector Cut-off Current				
	: MJD47	$V_{CE} = 350, V_{EB} = 0$		0.1	mA
	: MJD50	$V_{CE} = 500, V_{EB} = 0$		0.1	mA
I _{EBO}	Emitter Cut-off Current	$V_{BE} = 5V, I_{C} = 0$		1	mA
h _{FE}	* DC Current Gain	$V_{CE} = 10V, I_{C} = 0.3A$	30	150	
		$V_{CE} = 10V, I_{C} = 1A$	10		
V _{CE} (sat)	* Collector-Emitter Saturation Voltage	$I_C = 1A, I_B = 0.2A$		1	V
V _{BE} (sat)	* Base-Emitter Saturation Voltage	$V_{CE} = 10A, I_{C} = 1A$	•	1.5	V
f _T	Current Gain Bandwidth Product	$V_{CE} = 10V, I_{C} = 0.2A$	10		MHz

^{*} Pulse Test: PW≤300µs, Duty Cycle≤2%

Typical Performance Characteristics

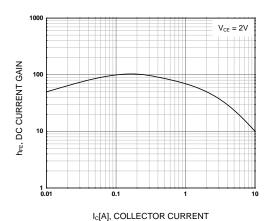


Figure 1. DC current Gain

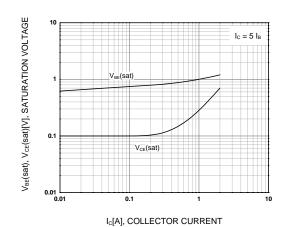


Figure 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

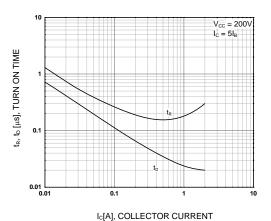


Figure 3. Turn On Time

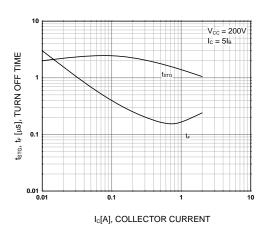


Figure 4. Turn Off Time

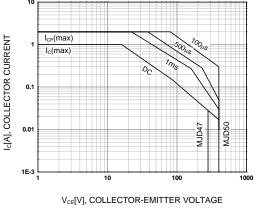


Figure 5. Safe Operating Area

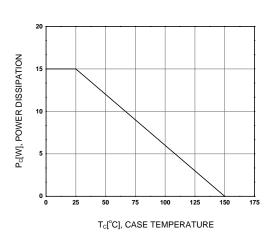
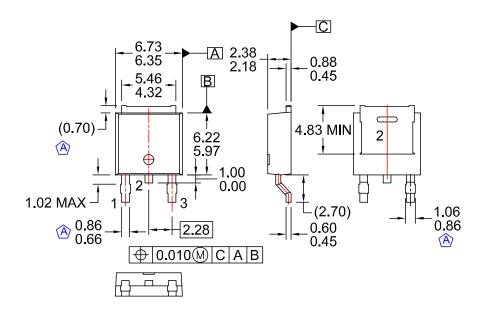


Figure 6. Power Derating

© 2012 Fairchild Semiconductor Corporation MJD47/50 Rev. B0 www.fairchildsemi.com

Physical Dimensions

D-PAK



NOTES: UNLESS OTHERWISE SPECIFIED

- (A) CONFORMS TO JEDEC TO-252 VARIATION AB EXCEPT WHERE NOTED
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DRAWING CONFORMS TO ASME Y14.5M-1994
- D) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.
- E) FORMERLY NAMED BD1733
- F) DRAWING FILE NAME: MKT-TO252D03REV1

Dimensions in Millimeters



山

TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

2CoolTM
AccuPowerTM
AX-CAP^{TM*}
BitSiCTM
Build it NowTM
CorePLUSTM
CorePOWERTM
CROSSVOLTTM

CTL™
Current Transfer Logic™

DEUXPEED®
Dual Cool™
EcoSPARK®
EfficientMax™
ESBC™

Fairchild®
Fairchild Semicon

Fairchild Semiconductor®
FACT Quiet Series™
FACT®
FAST®
FastvCore™

FETBench™ FlashWriter®* FPS™ F-PFS™ FRFET®

Global Power Resource^S GreenBridge[™] Green FPS[™] Green FPS[™] e-Series[™]

Gmax[™] GTO[™] IntelliMAX[™] ISOPLANAR[™]

Making Small Speakers Sound Louder

and Better™
MegaBuck™
MICROCOUPLER™
MicroFET™
MicroPak™
MicroPak2™
MilerDrive™
MotionMax™
Motion-SPM™
mWSaver™
OptoHit™

OPTOLOGIC®

OPTOPLANAR®

PowerTrench® PowerXS™

Programmable Active Droop™

QFET[®]
QS™
Quiet Series™
RapidConfigure™

Saving our world, 1mW/W/kW at a time™ SignalWise™

SmartMax™ SMART START™

Solutions for Your Success™

SPM[®]
STEALTH™
SuperFET[®]
SuperSOT™-3

SuperSOTTM-3 SuperSOTTM-6 SuperSOTTM-8 SupreMOS® SyncFETTM Sync-LockTM SYSTEM GENERAL®* The Power Franchise®

the franchise
FinyBoost™
FinyBoost™
FinyBuck™
FinyCalc™
FinyLogic®
FinyOPTO™
FinyPower™
FinyPwM™
FinyWire™
FransiC™
FriFault Detect™
TRUECURRENT®*
μSerDes™

SerDes"
UHC®
Ultra FRFET™
UniFET™
VCX™
VisualMax™
VoltagePlus™
XS™

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN, NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

- Life support devices or systems are devices or systems which, (a)
 are intended for surgical implant into the body or (b) support or
 sustain life, and (c) whose failure to perform when properly used in
 accordance with instructions for use provided in the labeling, can be
 reasonably expected to result in a significant injury of the user.
- A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address any warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Definition of Terms		
Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

Rev. I61

^{*} Trademarks of System General Corporation, used under license by Fairchild Semiconductor.